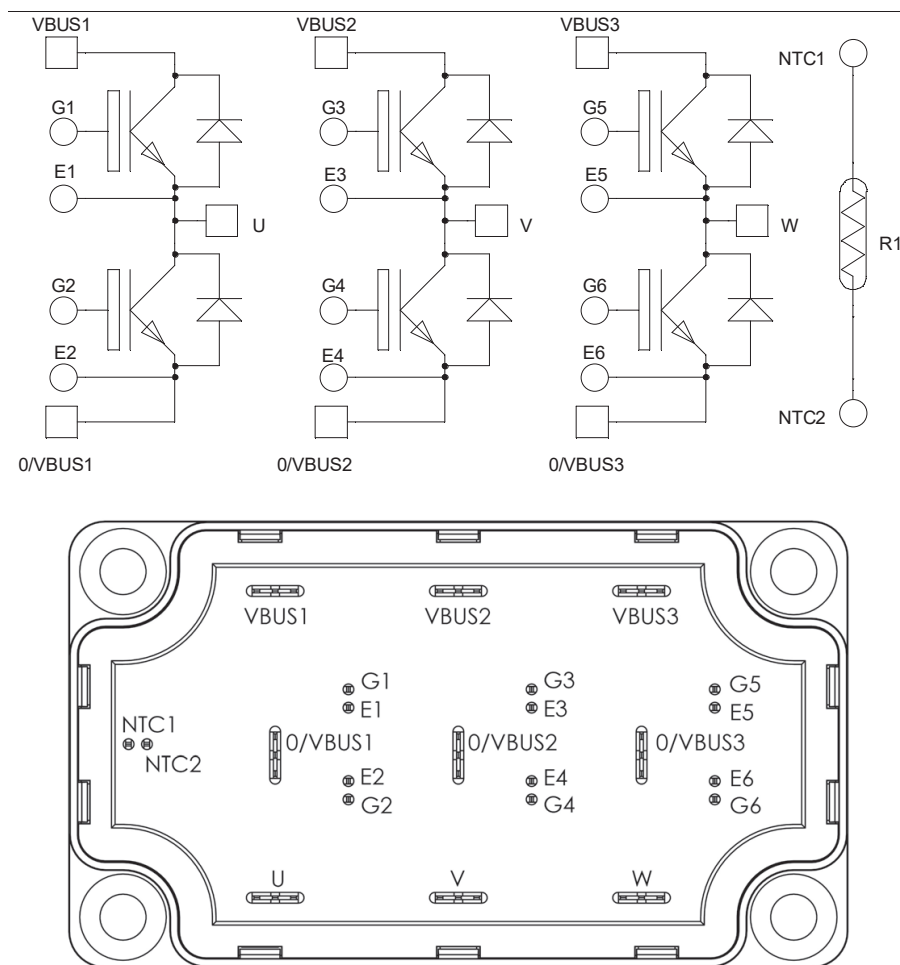


## Triple Phase Leg High-Speed IGBT 5 Power Module

### Product Overview

The APTGTQ150TA65TPG device is a three phase leg 650V, 150A Insulated-Gate Bipolar Transistor (IGBT) 5 power module.



**Note:** All ratings at  $T_J = 25^\circ\text{C}$ , unless otherwise specified.



These devices are sensitive to electrostatic discharge. Proper handling procedures must be followed.

## Features

The following are the key features of APTGTQ150TA65TPG device:

- High-Speed IGBT 5
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 100 kHz
  - Low leakage current
- Kelvin emitter for easy drive
- Very low stray inductance
- Lead frames for power connectors
- High level of integration
- Internal thermistor for temperature monitoring

## Benefits

The following are the benefits of APTGTQ150TA65TPG device:

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction-to-case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS compliant

## Applications

The following are the applications of APTGTQ150TA65TPG device:

- Welding converters
- Switched mode power supplies
- Uninterruptible power supplies
- Motor control

## 1. Electrical Specifications

The following sections show the electrical specifications of the APTGTQ150TA65TPG device.

### 1.1 IGBT Characteristics (Per IGBT)

The following table lists the absolute maximum ratings (per IGBT) of the APTGTQ150TA65TPG device.

**Table 1-1. Absolute Maximum Ratings**

Symbol	Parameter		Maximum Ratings	Unit
$V_{CES}$	Collector-Emitter voltage		650	V
$I_C$	Continuous collector current	$T_C = 25\text{ }^{\circ}\text{C}$	150	A
		$T_C = 80\text{ }^{\circ}\text{C}$	90	
$I_{CM}$	Pulsed collector current	$T_C = 25\text{ }^{\circ}\text{C}$	300	
$V_{GE}$	Gate-Emitter voltage		$\pm 20$	V
$P_D$	Power dissipation		365	W

The following table lists the electrical characteristics (per IGBT) of the APTGTQ150TA65TPG device.

**Table 1-2. Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min.	Typ.	Max.	Unit
$I_{CES}$	Zero gate voltage collector current	$V_{GE} = 0V$ ; $V_{CE} = 650V$		—	—	150	$\mu A$
$V_{CE(sat)}$	Collector emitter saturation voltage	$V_{GE} = 15V$ $I_C = 150A$	$T_J = 25\text{ }^{\circ}\text{C}$	—	1.65	2.2	V
			$T_J = 150\text{ }^{\circ}\text{C}$	—	1.9	—	
$V_{GE(th)}$	Gate threshold voltage	$V_{GE} = V_{CE}$ ; $I_C = 1.5\text{ mA}$		3.3	4.0	4.7	V
$I_{GES}$	Gate-Emitter leakage current	$V_{GE} = 20V$ ; $V_{CE} = 0V$		—	—	360	nA

# APTGTQ150TA65TPG

## Electrical Specifications

The following table lists the dynamic characteristics (per IGBT) of the APTGTQ150TA65TPG device.

**Table 1-3. Dynamic Characteristics**

Symbol	Characteristic	Test Conditions		Min.	Typ.	Max.	Unit
$C_{ies}$	Input capacitance	$V_{GE} = 0V$		—	9000	—	pF
$C_{oes}$	Output capacitance	$V_{CE} = 25V$		—	150	—	
$C_{res}$	Reverse transfer capacitance	$f = 1\text{ MHz}$		—	33	—	
$Q_G$	Gate charge	$V_{GE} = 15V$ $V_{CE} = 520V$ $I_C = 150A$		—	360	—	nC
$T_{d(on)}$	Turn-on delay time	$V_{GE} = 15V$	$T_J = 150\text{ }^\circ\text{C}$	—	20	—	ns
$T_r$	Rise time	$V_{Bus} = 400V$		—	15	—	
$T_{d(off)}$	Turn-off delay time	$I_C = 75A$		—	205	—	
$T_f$	Fall time	$R_G = 1\Omega$		—	26	—	
$E_{on}$	Turn-on energy	$V_{GE} = 15V$	$T_J = 150\text{ }^\circ\text{C}$	—	2.25	—	mJ
$E_{off}$	Turn-off energy	$V_{Bus} = 400V$ $I_C = 75A$ $R_G = 1\Omega$	$T_J = 150\text{ }^\circ\text{C}$	—	0.9	—	
$R_{Gint}$	Internal gate resistance			—	1.7	—	$\Omega$
$R_{thJC}$	Junction-to-case thermal resistance			—	—	0.41	$^\circ\text{C/W}$

## 1.2 Diode Ratings and Characteristics (Per Diode)

The following table lists the diode ratings and characteristics of the APTGTQ150TA65TPG device.

**Table 1-4. Diode Ratings and Characteristics**

Symbol	Characteristic	Test Conditions		Min.	Typ.	Max.	Unit
V <sub>RRM</sub>	Peak repetitive reverse voltage			—	—	650	V
I <sub>RM</sub>	Reverse leakage current	V <sub>R</sub> = 650V		—	—	50	μA
I <sub>F</sub>	DC forward current		T <sub>C</sub> = 25 °C	—	75	—	A
V <sub>F</sub>	Diode forward voltage	I <sub>F</sub> = 75A	T <sub>J</sub> = 25 °C	—	1.35	1.9	V
		V <sub>GE</sub> = 0V	T <sub>J</sub> = 150 °C	—	1.3	—	
t <sub>rr</sub>	Reverse recovery time	I <sub>F</sub> = 37.5A	T <sub>J</sub> = 25 °C	—	50	—	ns
		V <sub>R</sub> = 400V	T <sub>J</sub> = 150 °C	—	41	—	
Q <sub>rr</sub>	Reverse recovery charge	di/dt = 1500A/μs	T <sub>J</sub> = 25 °C	—	0.6	—	μC
			T <sub>J</sub> = 150 °C	—	1.2	—	
R <sub>thJC</sub>	Junction-to-case thermal resistance			—	—	1	°C/W

### 1.3 Thermal and Package Characteristics

The following table lists the thermal and package characteristics of the APTGTQ150TA65TPG device.

**Table 1-5. Thermal and Package Characteristics**

Symbol	Characteristic			Min.	Max.	Unit
V <sub>ISOL</sub>	RMS isolation voltage, any terminal to case t = 1 min, 50 Hz/60 Hz			4000	—	V
T <sub>J</sub>	Operating junction temperature range			−40	175	°C
T <sub>JOP</sub>	Recommended junction temperature under switching conditions			−40	T <sub>Jmax</sub> −25	
T <sub>STG</sub>	Storage case temperature			−40	125	
T <sub>C</sub>	Operating case temperature			−40	125	
Torque	Mounting torque	To heatsink	M6	3	5	N.m
Wt	Package weight			—	250	g

The following table lists the temperature sensor NTC of the APTGTQ150TA65TPG device.

**Table 1-6. Temperature Sensor NTC**

Symbol	Characteristic		Min.	Typ.	Max.	Unit
R <sub>25</sub>	Resistance at 25 °C		—	50	—	kΩ
ΔR <sub>25</sub> /R <sub>25</sub>	—		—	5	—	%
B <sub>25/85</sub>	T <sub>25</sub> = 298.15K		—	3952	—	K
ΔB/B	—	T <sub>C</sub> = 100 °C	—	4	—	%

$$R_T = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$

T: Thermistor temperature  
R<sub>T</sub>: Thermistor value at T

**Note:** See [APT0406—Using NTC Temperature Sensor Integrated into Power Module](#) for more information.

### 1.4 Typical IGBT Performance Curve

The following figures show the IGBT performance curves of the APTGTQ150TA65TPG device.

Figure 1-1. Maximum Thermal Impedance

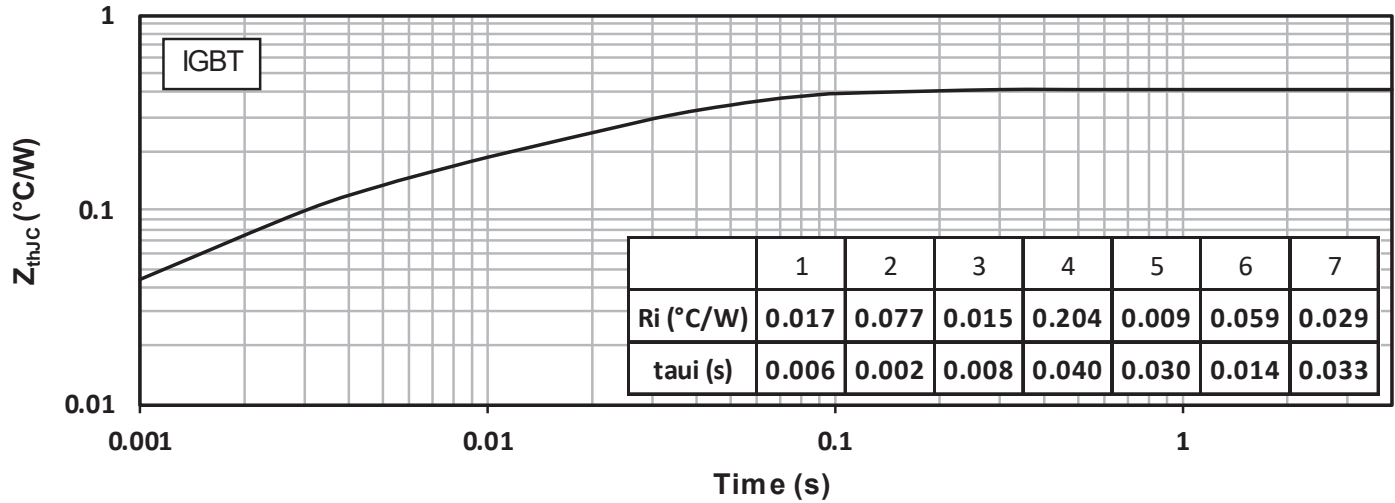


Figure 1-2. Output Characteristics,  $V_{GE} = 15V$

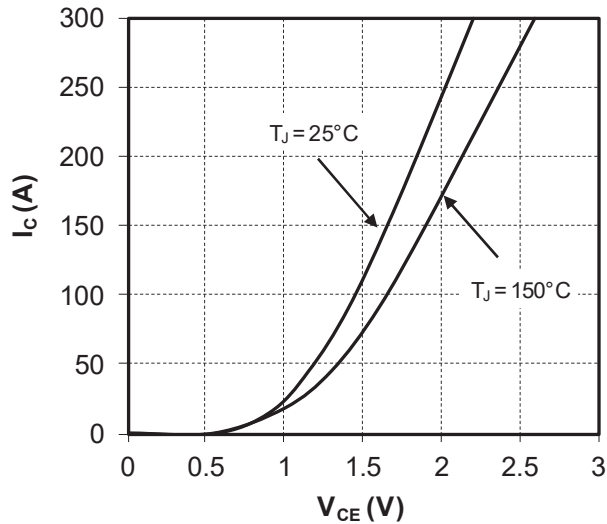
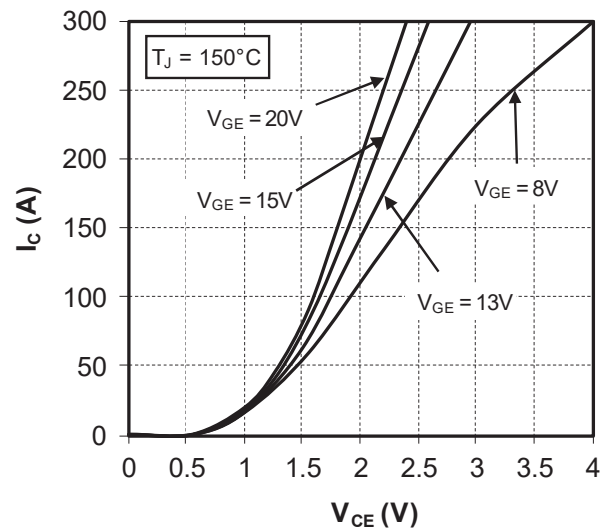


Figure 1-3. Output Characteristics,  $T_J = 150^\circ C$



# APTGTQ150TA65TPG

## Electrical Specifications

Figure 1-4. Transfer Characteristics

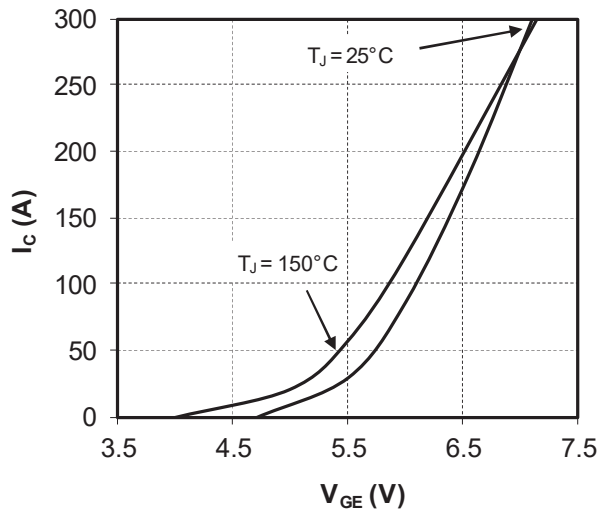


Figure 1-5. Energy Losses vs. Collector Current

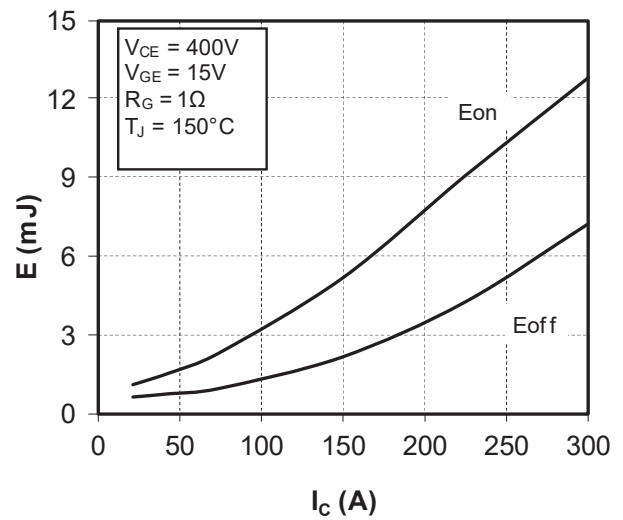


Figure 1-6. Switching Energy vs. Gate Resistance

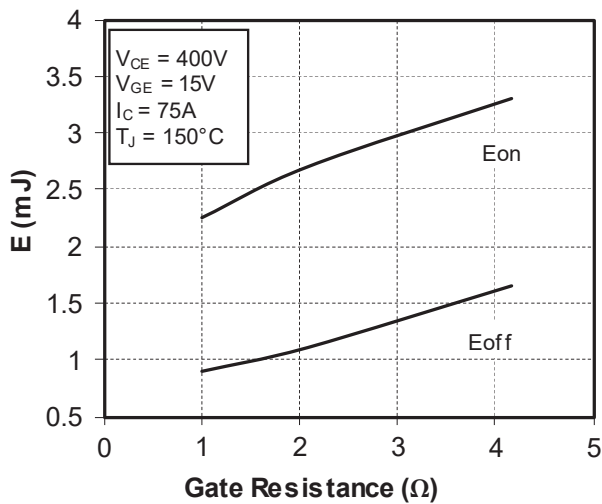
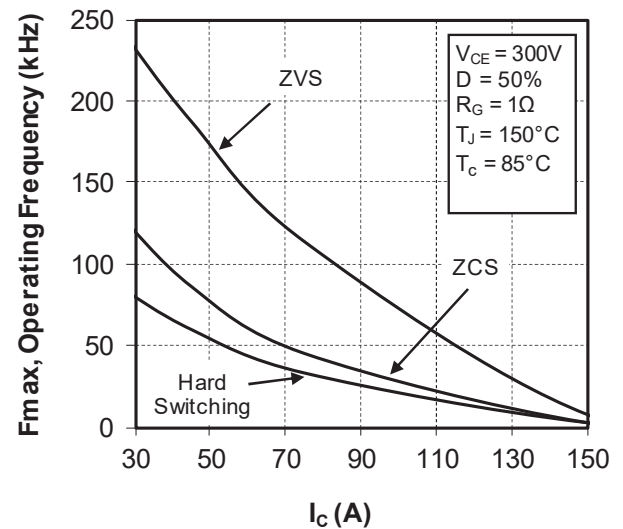


Figure 1-7. Operating Frequency vs Collector Current



### 1.5 Typical Diode Performance Curve

The following figures show the diode performance curves of the APTGTQ150TA65TPG device.

Figure 1-8. Maximum Thermal Impedance

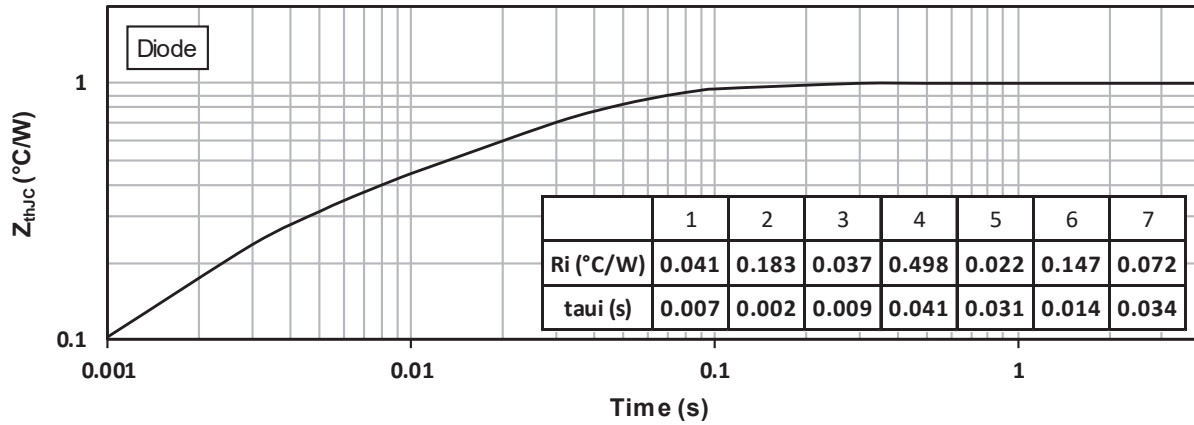
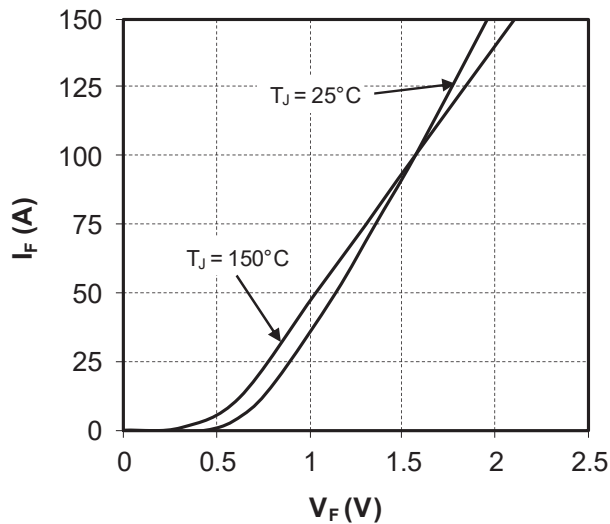


Figure 1-9. Diode Forward Characteristics





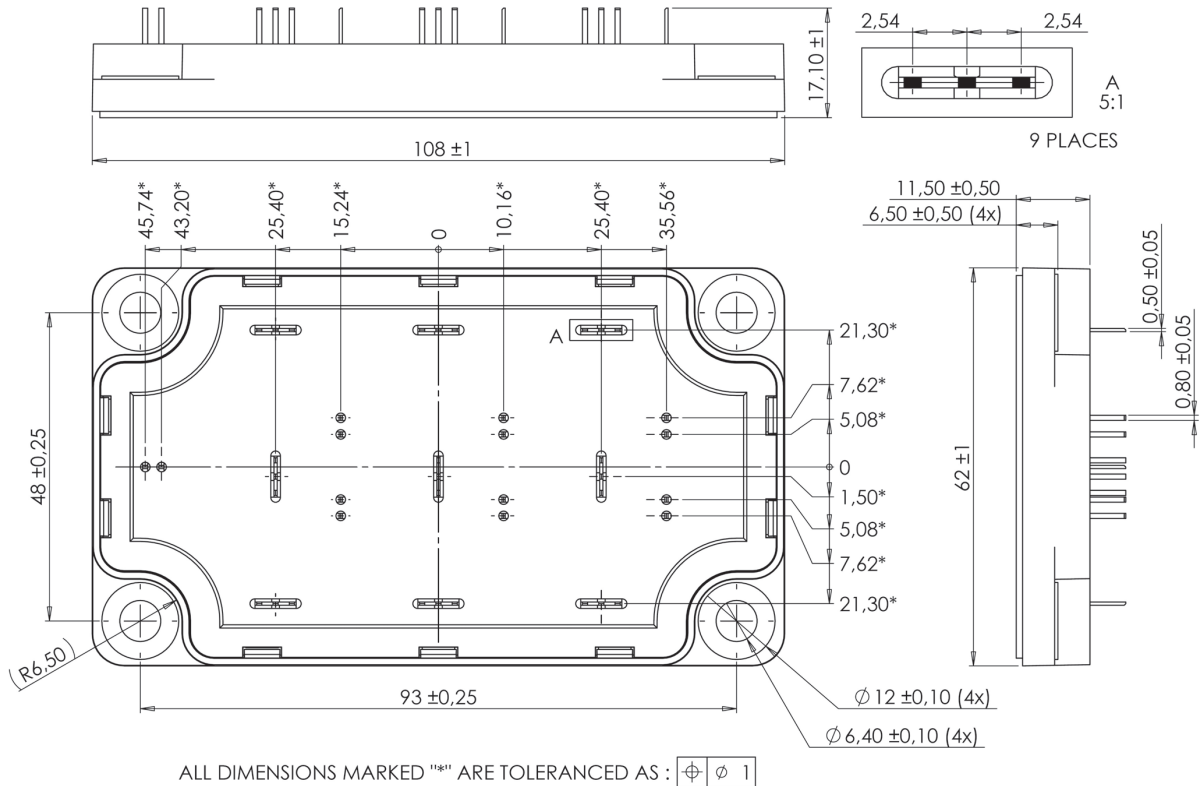
## 2. Package Specifications

The following section shows the package specification of the APTGTQ150TA65TPG device.

### 2.1 Package Outline

The following figure shows the package outline drawing of the APTGTQ150TA65TPG device. The dimensions in the following figure are in millimeters.

**Figure 2-1. Package Outline Drawing**



**Note:** See [1902—Mounting Instructions for SP6-P \(12 mm\) Power Modules](#) for more information.

### 3. Revision History

The revision history describes the changes that were implemented in the document. The changes are listed by revision, starting with the most current publication.

Revision	Date	Description
A	11/2022	Initial Revision

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